

2SC5419

Silicon NPN triple diffusion planar type

For low-frequency output amplification

■ Features

- High collector-emitter voltage (Base open) V_{CEO}
- High transition frequency f_T
- Allowing supply with the radial taping

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	300	V
Collector-emitter voltage (Base open)	V_{CEO}	300	V
Emitter-base voltage (Collector open)	V_{EBO}	7	V
Collector current	I_C	70	mA
Peak collector current	I_{CP}	100	mA
Collector power dissipation *	P_C	1	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Note) *: Copper plate at the collector is more than 1 cm^2 in area, 1.7 mm in thickness

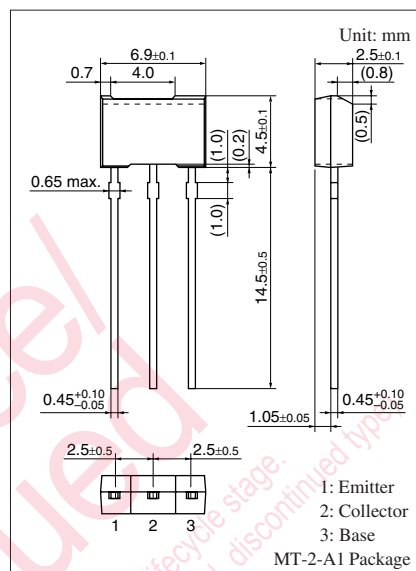
■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

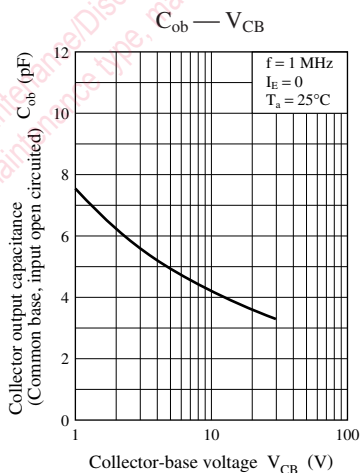
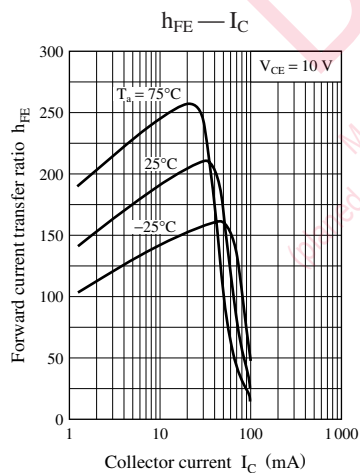
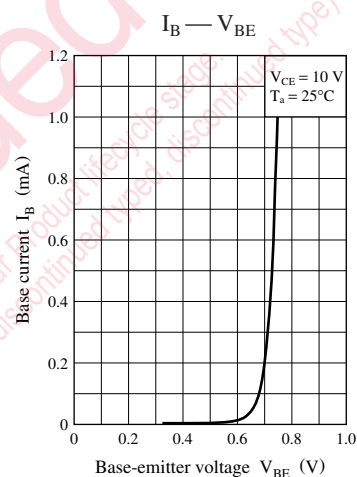
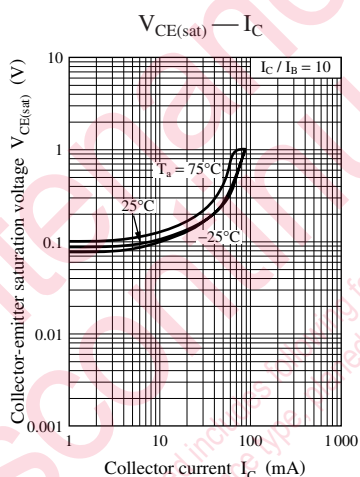
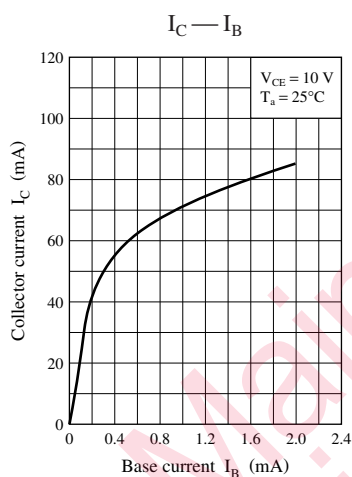
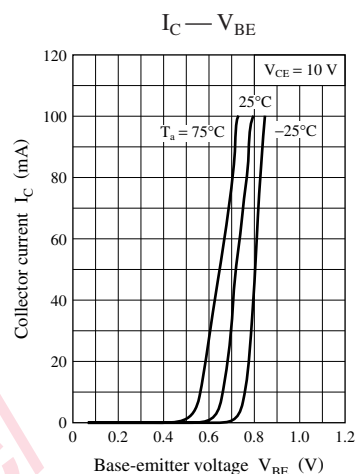
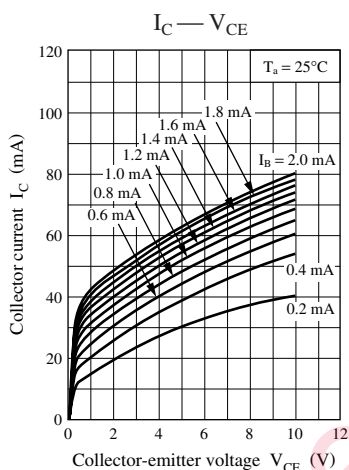
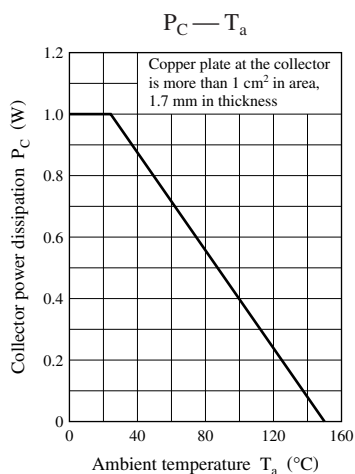
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 100\text{ }\mu\text{A}$, $I_B = 0$	300			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 1\text{ }\mu\text{A}$, $I_C = 0$	7			V
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 120\text{ V}$, $I_B = 0$			1	μA
Forward current transfer ratio *	h_{FE}	$V_{CE} = 10\text{ V}$, $I_C = 5\text{ mA}$	30		220	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 50\text{ mA}$, $I_B = 5\text{ mA}$			1.2	V
Transition frequency	f_T	$V_{CB} = 10\text{ V}$, $I_E = -10\text{ mA}$, $f = 200\text{ MHz}$	50			MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = 10\text{ V}$, $I_E = 0$, $f = 1\text{ MHz}$			10	pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	P	Q	R
h_{FE}	30 to 100	60 to 150	100 to 220





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